74HC4851-Q100; 74HCT4851-Q100

8-channel analog multiplexer/demultiplexer with injection-current effect control

Rev. 4 — 15 May 2023

Product data sheet

1. General description

The 74HC4851-Q100; 74HCT4851-Q100 are high-speed Si-gate CMOS devices and are specified in compliance with JEDEC standard no. 7A.

The 74HC4851-Q100; 74HCT4851-Q100 are 8-channel analog multiplexers/demultiplexers with three digital select inputs (S0 to S2), an active-LOW enable input (E), eight independent inputs/outputs (Y0 to Y7) and a common input/output (Z). The devices feature injection-current effect control, which has excellent value in automotive applications where voltages in excess of the supply voltage are common.

With \overline{E} LOW, one of the eight switches is selected (low impedance ON-state) by S0 to S2. With \overline{E} HIGH, all switches are in the high-impedance OFF-state, independent of S0 to S2.

The injection-current effect control allows signals at disabled analog input channels to exceed the supply voltage without affecting the signal of the enabled analog channel. This eliminates the need for external diode/resistor networks typically used to keep the analog channel signals within the supply-voltage range.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Injection-current cross coupling < 1 mV/mA
- Wide supply voltage range from 2.0 V to 6.0 V for 74HC4851-Q100
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Latch-up performance exceeds 100 mA per JESD 78 Class II level A
- Low ON-state resistance:
 - 400 Ω (typical) at V_{CC} = 2.0 V
 - 215 Ω (typical) at V_{CC} = 3.0 V
 - 120 Ω (typical) at V_{CC} = 3.3 V
 - 76 Ω (typical) at V_{CC} = 4.5 V
 - 59 Ω (typical) at V_{CC} = 6.0 V
- Multiple package options
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

3. Applications

- · Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating
- Automotive application

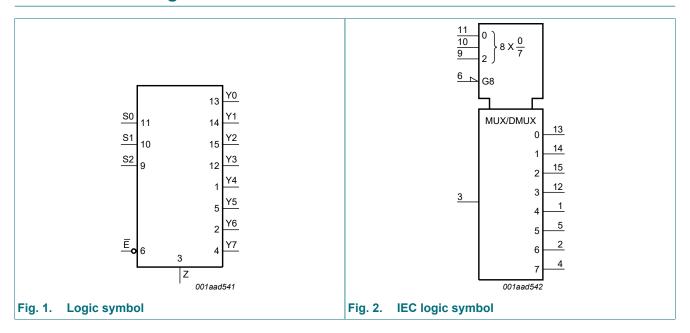


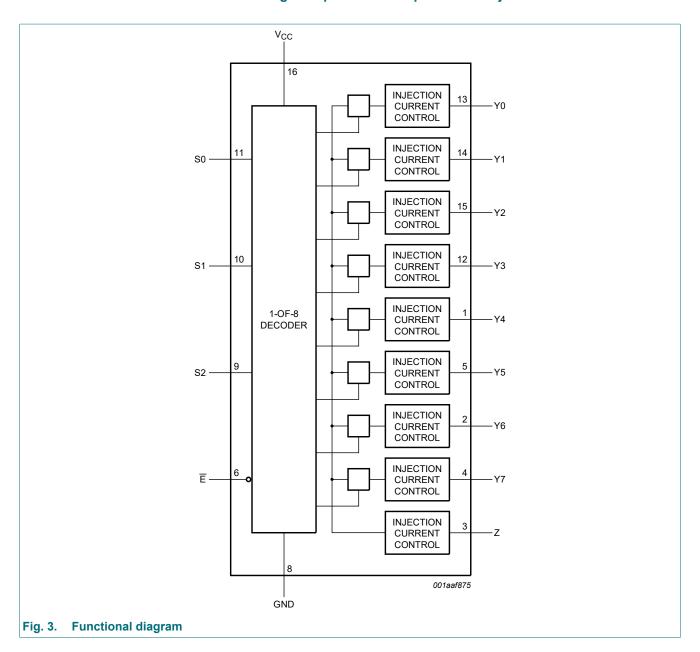
4. Ordering information

Table 1. Ordering information

Type number	Package										
	Temperature range	Name	Description	Version							
74HC4851D-Q100 74HCT4851D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1							
74HC4851PW-Q100 74HCT4851PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1							
74HC4851BQ-Q100 74HCT4851BQ-Q100	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm	SOT763-1							

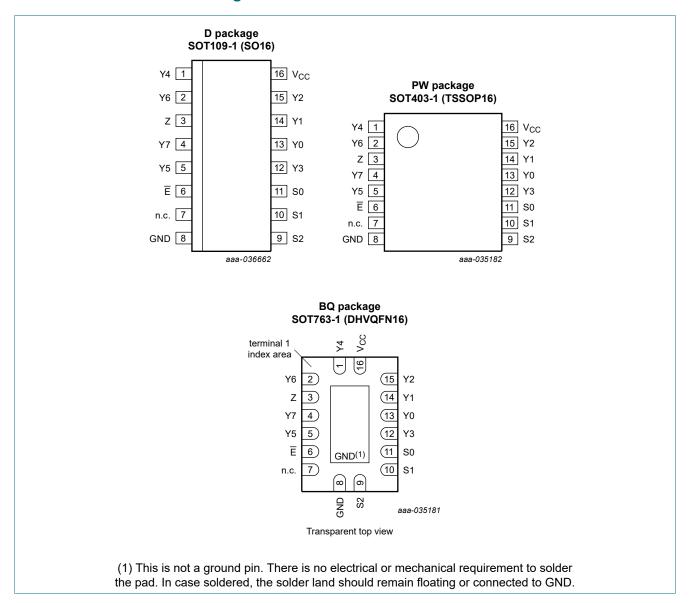
5. Functional diagram





6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
Y4, Y6, Y7, Y5, Y3, Y0, Y1, Y2	1, 2, 4, 5, 12, 13, 14, 15	independent input/output
Z	3	common input/output
E	6	enable input (active LOW)
n.c.	7	not connected
GND	8	ground (0 V)
S2, S1, S0	9, 10, 11	select input
V _{CC}	16	supply voltage

7. Functional description

Table 3. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care.$

Input				Channel ON
Ē	S2	S1	S0	
L	L	L	L	Y0 to Z
L	L	L	Н	Y1 to Z
L	L	Н	L	Y2 to Z
L	L	Н	Н	Y3 to Z
L	Н	L	L	Y4 to Z
L	Н	L	Н	Y5 to Z
L	Н	Н	L	Y6 to Z
L	Н	Н	Н	Y7 to Z
Н	X	X	X	-

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage	[1]	-0.5	V _{CC} + 0.5	V
V_{SW}	switch voltage	[2]	-0.5	V _{CC} + 0.5	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{SK}	switch clamping current	V_{SW} < -0.5 V or V_{SW} > V_{CC} + 0.5 V	-	±20	mA
I _{SW}	switch current	$V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	50	mA
I_{GND}	ground current		-50	-	mA
T_{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$ [3]	-	500	mW

- [1] The minimum and maximum input voltage rating may be exceeded if the input clamping current rating is observed.
- [2] The minimum and maximum switch voltage rating may be exceeded if the switch clamping current rating is observed.
- [3] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C. For SOT763-1 (DHVQFN16) package: P_{tot} derates linearly with 11.2 mW/K above 106 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74H	C4851-0	Q100	74H0	CT4851-	Q100	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	-	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
V _{SW}	switch voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	6.0	1000	-	-	-	ns/V
		V _{CC} = 3.0 V	-	6.0	800	-	-	-	ns/V
		V _{CC} = 3.3 V	-	6.0	800	-	-	-	ns/V
		V _{CC} = 4.5 V	-	6.0	500	-	6.0	500	ns/V
		V _{CC} = 6.0 V	-	6.0	400	-	-	-	ns/V

10. Static characteristics

Table 6. R_{ON} resistance

At recommended operating conditions; voltages are referenced to GND (ground 0 V); For test circuit see Fig. 6.

Symbol	Parameter	Conditions	25 °C			C to		°C to 5 °C	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
74HC485	1-Q100									
R _{ON(peak)}		$V_I = V_{CC}$ to GND; $\overline{E} = V_{IL}$								
	(peak)	V _{CC} = 2.0 V; I _{SW} = 2 mA	-	400	650	-	670	-	700	Ω
		V _{CC} = 3.0 V; I _{SW} ≤ 2 mA	-	215	330	-	360	-	380	Ω
		$V_{CC} = 3.3 \text{ V}; I_{SW} \le 2 \text{ mA}$	-	120	270	-	305	-	345	Ω
		V _{CC} = 4.5 V; I _{SW} ≤ 2 mA	-	76	210	-	240	-	270	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} \le 2 \text{ mA}$	-	59	195	-	220	-	250	Ω
ΔR _{ON}	ON resistance	$V_I = 0.5 \times V_{CC}; \overline{E} = V_{IL}$								
n	mismatch between	V _{CC} = 2.0 V; I _{SW} = 2 mA	-	4	10	-	15	-	20	Ω
	channels	$V_{CC} = 3.0 \text{ V}; I_{SW} \le 2 \text{ mA}$	-	2	8	-	12	-	16	Ω
		V _{CC} = 3.3 V; I _{SW} ≤ 2 mA	-	2	8	-	12	-	16	Ω
		V _{CC} = 4.5 V; I _{SW} ≤ 2 mA	-	2	8	-	12	-	16	Ω
		V _{CC} = 6.0 V; I _{SW} ≤ 2 mA	-	3	9	-	13	-	18	Ω
74HCT48	51-Q100		'							
R _{ON(peak)}	ON resistance	$V_I = V_{CC}$ to GND; $\overline{E} = V_{IL}$								
	(peak)	V _{CC} = 4.5 V; I _{SW} ≤ 2 mA	-	76	210	-	240	-	270	Ω
ΔR _{ON}	ON resistance	$V_I = 0.5 \times V_{CC}; \overline{E} = V_{IL}$								
	mismatch between channels	V _{CC} = 4.5 V; I _{SW} ≤ 2 mA	-	2	8	-	12	-	16	Ω

Table 7. Injection current coupling

At recommended operating conditions; voltages are referenced to GND (ground 0 V); For test circuit see Fig. 7.

				. •	•		•		
Symbol	Parameter	Conditions	74F	IC4851-Q	100	74HCT4851-Q100			Unit
			Min	Typ [1]	Max	Min	Typ [1]	Max	
T _{amb} = -4	10 °C to +125 °C	}							
ΔV _O	output voltage variation	$ I_{SW} \le 1 \text{ mA}; R_S \le 3.9 \text{ k}\Omega$ [2]							
		V _{CC} = 3.3 V	-	0.05	1	-	-	-	mV
		V _{CC} = 5.0 V	-	0.03	1	-	0.03	1	mV
		$ I_{SW} \le 10 \text{ mA}; R_S \le 3.9 \text{ k}\Omega$							
		V _{CC} = 3.3 V	-	0.55	5	-	-	-	mV
		V _{CC} = 5.0 V	-	0.27	5	-	0.27	5	mV
		$ I_{SW} \le 1 \text{ mA}; R_S \le 20 \text{ k}\Omega$							
		V _{CC} = 3.3 V	-	0.04	2	-	-	-	mV
		V _{CC} = 5.0 V	-	0.03	2	-	0.03	2	mV
		$ I_{SW} \le 10 \text{ mA}; R_S \le 20 \text{ k}\Omega$							
		V _{CC} = 3.3 V	-	0.56	20	-	-	-	mV
		V _{CC} = 5.0 V	-	0.48	20	-	0.48	20	mV

^[1] Typical values are measured at T_{amb} = 25 °C.

Table 8. Static characteristics

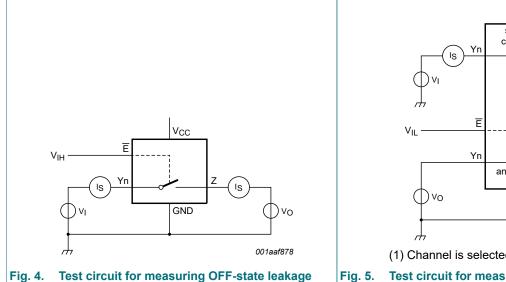
At recommended operating conditions; voltages are referenced to GND (ground 0 V);

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	_	°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC48	51-Q100		'		'					
V_{IH}	HIGH-level	control inputs								
	input voltage	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
		V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 3.3 V	2.3	-	-	2.3	-	2.3	-	V
		V _{CC} = 4.5 V	3.15	-	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	-	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	control inputs								
	input voltage	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
		V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V _{CC} = 3.3 V	-	-	1.0	-	1.0	-	1.0	V
		V _{CC} = 4.5 V	-	-	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	-	1.8	-	1.8	V

^[2] ΔV_0 here is the maximum variation of output voltage of an enabled analog channel when current is injected into any disabled channel.

^[3] I_{SW} = total current injected into all disabled channels.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	_	°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
Ι _Ι	input leakage current	control inputs; V_I = GND or V_{CC} ; V_{CC} = 6.0 V	-	-	±0.1	-	±0.1	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	\overline{E} = V _{IH} ; V _I = GND or V _{CC} ; V _O = V _{CC} or GND; V _{CC} = 6.0 V; see <u>Fig. 4</u>								
		per channel	-	-	±0.1	-	±0.5	-	±1.0	μΑ
		all channels	-	-	±0.2	-	±2.0	-	±4.0	μΑ
I _{S(ON)}	ON-state leakage current	\overline{E} = V _{IL} ; V _I = GND or V _{CC} ; V _O = V _{CC} or GND; V _{CC} = 6.0 V; see <u>Fig. 5</u>	-	-	±0.1	-	±0.5	-	±1.0	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	2.0	-	5.0	-	20.0	μΑ
C _I	input capacitance	S0, S1, S2 and E	-	2	10	-	10	-	10	pF
C _{sw}	switch	Z; OFF-state	-	15	40	-	40	-	40	pF
	capacitance	Yn; OFF-state	-	3	15	-	15	-	15	pF
74HCT4	851-Q100									
V _{IH}	HIGH-level input voltage	control inputs; V _{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	control inputs; V _{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
l _l	input leakage current	control inputs; V_I = GND or V_{CC} ; V_{CC} = 5.5 V	-	-	±0.1	-	±0.1	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	\overline{E} = V _{IH} ; V _I = GND or V _{CC} ; V _O = V _{CC} or GND; V _{CC} = 5.5 V; see <u>Fig. 4</u>								
		per channel	-	-	±0.1	-	±0.5	-	±1.0	μΑ
		all channels	-	-	±0.2	-	±2.0	-	±4.0	μΑ
I _{S(ON)}	ON-state leakage current	$E = V_{IL}$; $V_I = GND$ or V_{CC} ; $V_O = V_{CC}$ or GND ; $V_{CC} = 5.5$ V; see Fig. 5	-	-	±0.1	-	±0.5	-	±1.0	μΑ
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	2.0	-	5.0	-	20.0	μΑ
Δl _{CC}	additional supply current control inputs; $V_1 = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_O = 0 \text{ A}$		-	-	300	-	370	-	370	μA
Cı	input capacitance	S0, S1, S2 and E	-	2	10	-	10	-	10	pF
C _{sw}	switch	Z; OFF-state	-	15	40	-	40	-	40	pF
	capacitance	Yn; OFF-state	-	3	15	-	15	-	15	pF



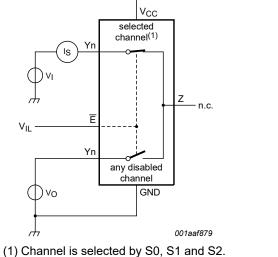
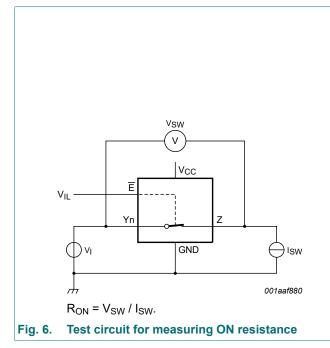
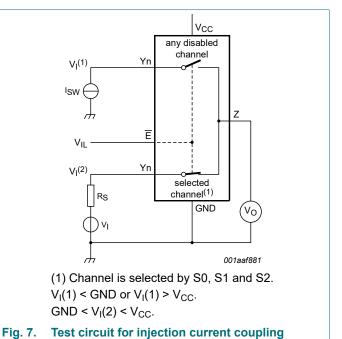


Fig. 5. Test circuit for measuring ON-state leakage current





11. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V); for test circuit see Fig. 12.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC48	51-Q100									
t _{pd}	propagation	Z to Yn, Yn to Z; see Fig. 8 [1]								
	delay	V _{CC} = 2.0 V	-	10.0	25	-	29	-	32	ns
		V _{CC} = 3.0 V	-	6.0	15.5	-	17.5	-	19.5	ns
		V _{CC} = 3.3 V	-	5.0	14.5	-	16.5	-	18.5	ns
		V _{CC} = 4.5 V	-	4.0	11.5	-	12.5	-	13.5	ns
		V _{CC} = 6.0 V	-	3.0	10	-	11	-	12	ns
		Sn to Z, Sn to Yn; see Fig. 9 [1]								
		V _{CC} = 2.0 V	-	18.0	32	-	35	-	40	ns
		V _{CC} = 3.0 V	-	9.5	17.5	-	20	-	23	ns
		V _{CC} = 3.3 V	-	8.5	16.5	-	19	-	22	ns
		V _{CC} = 4.5 V	-	6.5	13	-	15	-	17	ns
		V _{CC} = 6.0 V	-	5.0	12.5	-	14.5	-	16.5	ns
t _{en}	enable time	Ē to Z, Ē to Yn; see Fig. 10 [2]								
		V _{CC} = 2.0 V	-	-	95	-	105	-	115	ns
		V _{CC} = 3.0 V	-	-	90	-	100	-	110	ns
		V _{CC} = 3.3 V	-	-	85	-	95	-	105	ns
		V _{CC} = 4.5 V	-	-	80	-	90	-	100	ns
		V _{CC} = 6.0 V	-	-	78	-	80	-	80	ns
t _{dis}	disable time	E to Z, E to Yn; see Fig. 10 [3]								
		V _{CC} = 2.0 V	-	-	99	-	105	-	115	ns
		V _{CC} = 3.0 V	-	-	90	-	100	-	110	ns
		V _{CC} = 3.3 V	-	-	85	-	95	-	105	ns
		V _{CC} = 4.5 V	-	-	80	-	90	-	100	ns
		V _{CC} = 6.0 V	-	-	78	-	80	-	80	ns
C _{PD}	power	per channel; see Fig. 11 [4]								
	dissipation	V _{CC} = 3.3 V	-	28	-	-	-	-	_	pF
	capacitance	V _{CC} = 5.0 V	-	33	-	-	-	-	-	pF

Symbol	Parameter	Conditions		25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
				Min	Тур	Max	Min	Max	Min	Max	
74HCT4	851-Q100										
t _{pd}	propagation	Z to Yn, Yn to Z; see Fig. 8	[1]								
	delay	V _{CC} = 4.5 V		1.6	3.7	11.5	1.1	12.5	1.1	13.5	ns
		Sn to Z, Sn to Yn; see Fig. 9	[1]								
		V _{CC} = 4.5 V		3.2	8.0	13	2.3	15	2.3	17	ns
t _{en}	enable time	Ē to Z, Ē to Yn; see Fig. 10	[2]								
		V _{CC} = 4.5 V		4.2	8.6	25	3.0	30	3.0	35	ns
t _{dis}	disable time	E to Z, E to Yn; see Fig. 10	[3]								
		V _{CC} = 4.5 V	:	28.5	64.7	80	28.2	90	28	100	ns
C _{PD}	power	per channel; see Fig. 11	[4]								
	dissipation capacitance	V _{CC} = 5.0 V		-	30	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [2] t_{en} is the same as t_{PZH} and t_{PZL}.
- [3] t_{dis} is the same as t_{PLZ} and t_{PHZ} .
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

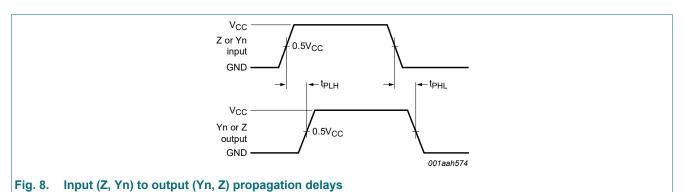
 $\sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = \text{sum of outputs};$

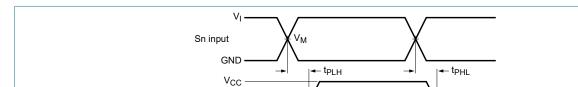
C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

11.1. Waveforms and test circuit





Measurement points are given in Table 10.

Yn or Z output GND

Fig. 9. Input (Sn) to output (Yn, Z) propagation delays

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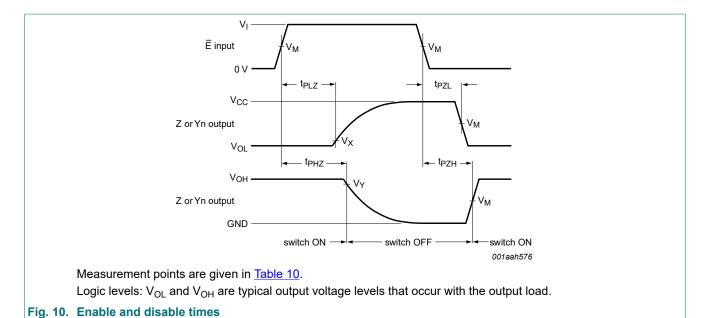
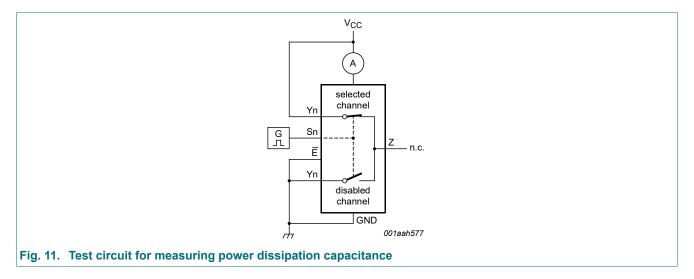


Table 10. Measurement points

Туре	Input		Output		
	V _M	VI	V _M	V _X	V _Y
74HC4851-Q100	0.5 × V _{CC}	V _{CC}	0.5 × V _{CC}	$V_{OL} + 0.1 \times (V_{CC} - V_{OL})$	0.9 × V _{OH}
74HCT4851-Q100	1.3 V	3.0 V	0.5 × V _{CC}	$V_{OL} + 0.1 \times (V_{CC} - V_{OL})$	0.9 × V _{OH}



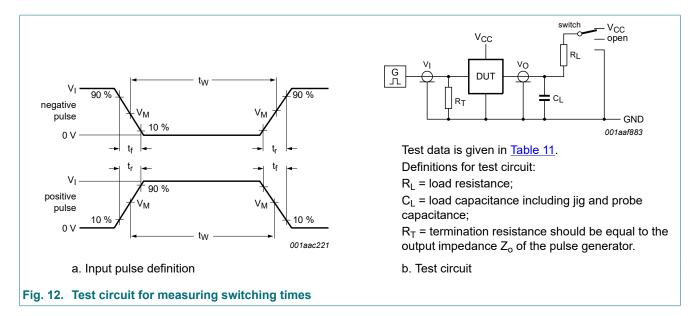


Table 11. Test data

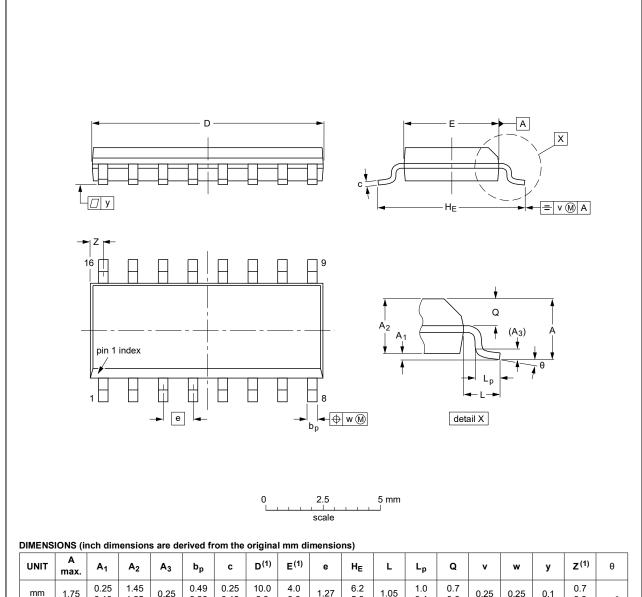
Test	Input			Output	S1 position	
	Control E , Sn	Switch Yn (Z)	t _r , t _f	Switch Z (Yn)		
	V _I [1]	V _I		C _L	R _L	
t _{PHL,} t _{PLH}	V _{CC}	V _{CC}	6 ns	50 pF	-	open
t _{PHZ} , t _{PZH}	V _{CC}	V _{CC}	6 ns	50 pF	10 kΩ	GND
t _{PLZ} , t _{PZL}	V _{CC}	V _{CC}	6 ns	50 pF	10 kΩ	V _{CC}
C _{PD}	V _{CC}	V _{CC}	6 ns	0 pF	-	open

[1] For 74HCT4851-Q100: input voltage $V_1 = 3.0 \text{ V}$.

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

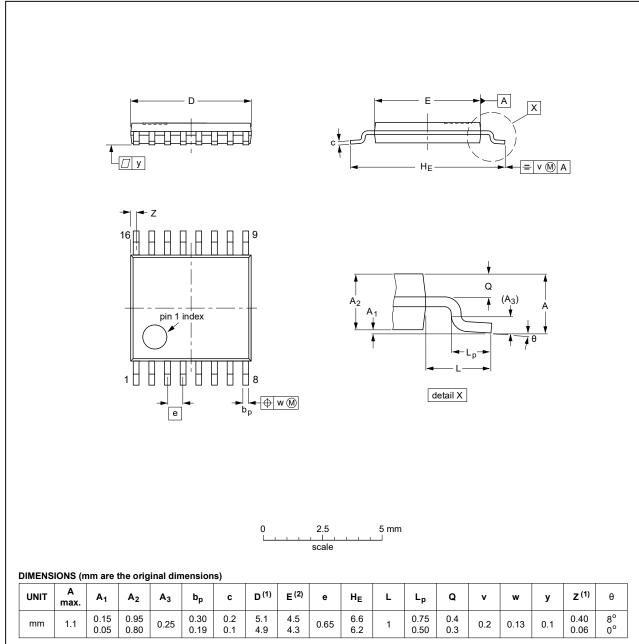
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig. 13. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				99-12-27 03-02-18	

Fig. 14. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

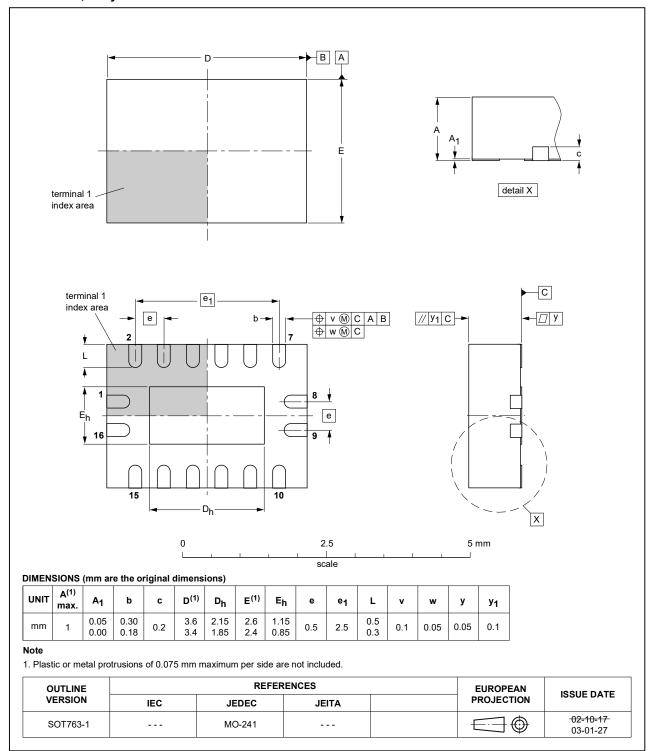


Fig. 15. Package outline SOT763-1 (DHVQFN16)

13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MIL	Military
MM	Machine Model

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT4851_Q100 v.4	20230515	Product data sheet	-	74HC_HCT4851_Q100 v.3			
Modifications:	Section 6.1 updated inline with 74HC_HCT4851.						
74HC_HCT4851_Q100 v.3	20200218	Product data sheet	-	74HC_HCT4851_Q100 v.2			
Modifications:	<u>Section 2</u> updated.						
74HC_HCT4851_Q100 v.2	20180824	Product data sheet	-	74HC_HCT4851_Q100 v.1			
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. 						
74HC_HCT4851_Q100 v.1	20120802	Product data sheet	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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